



**Automotive New Product Qualification Summary
(As per AEC-Q100 / Q006 and JEDEC Guidelines)**

**LM2903BQDGKRQ1
Approved 02-Jul-2021**

Product Attributes

| Attributes | Qual Device: <u>LM2903BQDGKRQ1</u> | QBS Product Reference: <u>LM2903BQDRQ1</u> | QBS Process Reference: <u>LM2904BQDRQ1</u> |
|------------------------|---------------------------------------|---|---|
| Automotive Grade Level | Grade 1 | Grade 1 | Grade 1 |
| Operating Temp Range | -40 to +125 C | -40 to +125 C | -40 to +125 C |
| Product Function | Signal Chain | Signal Chain | Signal Chain |
| Wafer Fab Supplier | CFAB | CFAB | CFAB |
| Die Revision | A0 | A0 | B |
| Assembly Site | HFTFAT | FMX | FMX |
| Package Type | VSSOP | SOIC | SOIC |
| Package Designator | DGK | D | D |
| Ball/Lead Count | 8 | 8 | 8 |

- QBS: Qual By Similarity
- Qual Device LM2903BQDGKRQ1 is qualified at LEVEL1-260C

Qualification Results

Data Displayed as: Number of lots / Total sample size / Total failed

| Type | # | Test Spec | Min Lot Qty | SS/Lot | Test Name / Condition | Duration | Qual Device: <u>LM2903BQDGKRQ1</u> | QBS Product Reference: <u>LM2903BQDRQ1</u> | QBS Process Reference: <u>LM2904BQDRQ1</u> |
|--|----|-----------------------------|-------------|--------|----------------------------|---------------|---------------------------------------|---|---|
| Test Group A – Accelerated Environment Stress Tests | | | | | | | | | |
| PC | A1 | JEDEC J-STD-020 JESD22-A113 | 3 | 77 | Automotive Preconditioning | MSL 1- 260C | 3/924/0 | - | - |
| HAST | A2 | JEDEC JESD22-A110 | 3 | 77 | Biased HAST, 110C/85%RH | 264/hrs @110C | 3/240/2 (1) | - | - |
| HAST | A2 | JEDEC JESD22-A110 | 3 | 77 | Biased HAST, 110C/85%RH | 528/hrs @110C | 3/210/0 | - | - |

| | Type | # | Test Spec | Min Lot Qty | SS/Lot | Test Name / Condition | Duration | Qual Device: <u>LM2903BQDGKRQ1</u> | QBS Product Reference: <u>LM2903BQDRQ1</u> | QBS Process Reference: <u>LM2904BQDRQ1</u> |
|---|------|----|----------------------------------|-------------|--------|---|-----------------------|---|---|---|
| | TC | A4 | JEDEC JESD22-A104 and Appendix 3 | 3 | 77 | Temperature Cycle, -65/150C | 500 Cycles | 3/231/0 | - | - |
| | TC | A4 | JEDEC JESD22-A104 and Appendix 3 | 3 | 77 | Temperature Cycle, -65/150C | 1000 Cycles | 3/210/0 | - | - |
| | PTC | A5 | JEDEC JESD22-A105 | 1 | 45 | Power Temperature Cycle | 1000 Cycles | N/A | - | - |
| | HTSL | A6 | JEDEC JESD22-A103 | 1 | 45 | High Temp Storage Bake 150C | 1000/ Hours | 3/231/0 | - | - |
| | HTSL | A6 | JEDEC JESD22-A103 | 1 | 45 | High Temp Storage Bake 150C | 2000 Hours | 3/228/0 | - | - |
| Test Group B – Accelerated Lifetime Simulation Tests | | | | | | | | | | |
| | HTOL | B1 | JEDEC JESD22-A108 | 3 | 77 | Life Test, 150C | 300 Hours | 1/77/0 | 3/231/0 | - |
| | ELFR | B2 | AEC Q100-008 | 3 | 800 | Early Life Failure Rate, 125C | 48 Hours | - | 1/800/0 | 3/2400/4 (2) |
| | EDR | B3 | AEC Q100-005 | 3 | 77 | NVM Endurance, Data Retention, and Operational Life | - | N/A | - | - |
| Test Group C – Package Assembly Integrity Tests | | | | | | | | | | |
| | WBS | C1 | AEC Q100-001 | 1 | 30 | Wire Bond Shear (Cpk>1.67) | - | - | - | - |
| | WBP | C2 | MIL-STD883 Method 2011 | 1 | 30 | Wire Bond Pull (Cpk>1.67) | - | - | - | - |
| | SD | C3 | JEDEC JESD22-B102 | 1 | 15 | Pb Free Surface Mount Solderability | Pb Free/Solderability | 1/15/0 | - | - |
| | SD | C3 | JEDEC JESD22-B102 | 1 | 15 | Pb Surface Mount Solderability | Pb Solderability | 1/15/0 | - | - |
| | PD | C4 | JEDEC JESD22-B100 and B108 | 3 | 10 | Physical Dimensions (Cpk>1.67) | - | 3/30/0 | - | - |
| | SBS | C5 | AEC Q100-010 | 3 | 50 | Solder Ball Shear (Cpk>1.67) | Solder Balls | N/A | - | - |
| | LI | C6 | JEDEC JESD22-B105 | 1 | 50 | Lead Integrity | - | - | - | - |
| Test Group D – Die Fabrication Reliability Tests | | | | | | | | | | |
| | EM | D1 | JESD61 | - | - | Electromigration | - | Completed Per Process Technology Requirements | - | - |
| | Tddb | D2 | JESD35 | - | - | Time Dependant Dielectric Breakdown | - | Completed Per Process Technology Requirements | - | - |
| | HCI | D3 | JESD60 & 28 | - | - | Hot Injection Carrier | - | Completed Per Process Technology Requirements | - | - |
| | NBTI | D4 | - | - | - | Negative Bias Temperature Instability | - | Completed Per Process Technology | - | - |

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|---|----|--------------|-------------|--------|--------------------------|-----------------------------------|---|---|---|
| | | | | | | | Requirements | | |
| SM | D5 | - | - | - | Stress Migration | - | Completed Per Process Technology Requirements | - | - |
| Test Group E – Electrical Verification Tests | | | | | | | | | |
| HBM | E2 | AEC Q100-002 | 1 | 3 | ESD - HBM - Q100 | 2000 V | 1/3/0 | - | - |
| CDM | E3 | AEC Q100-011 | 1 | 3 | ESD - CDM - Q100 | 1500 V | 1/3/0 | - | - |
| LU | E4 | AEC Q100-004 | 1 | 6 | Latch-up | (Per AEC-Q100-004) | 1/6/0 | - | - |
| ED | E5 | AEC Q100-009 | 3 | 30 | Electrical Distributions | Cpk>1.67 Room, hot, and cold test | 3/90/0 | - | - |

A1 (PC): Preconditioning:

Performed for THB, Biased HAST, AC, uHAST, TC & PTC samples, as applicable.

Note (1): fails due to wire bond corrosion. See FA attached to eQDB

Note (2): ELFR fails due to a defect screenable at production test. See 8D attached to eQDB

Ambient Operating Temperature by Automotive Grade Level:

Grade 0 (or E): -40°C to +150°C

Grade 1 (or Q): -40°C to +125°C

Grade 2 (or T): -40°C to +105°C

Grade 3 (or I) : -40°C to +85°C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level):

Room/Hot/Cold : HTOL, ED

Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU

Room : AC/uHAST

Green/Pb-free Status:

Qualified Pb-Free(SMT) and Green

TI Qualification ID: 20190802-130791

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